

Description

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

The 74AUP2G07 is composed of two buffers with open drain outputs designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down. The gates perform the positive Boolean function:

$$Y = A$$

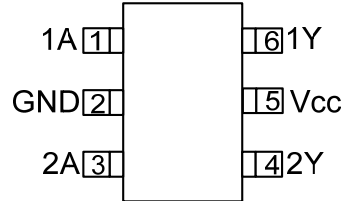
Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- -4mA Output Drive at 3.0V
- Low Static power consumption
- $I_{CC} < 0.9\mu A$
- Low Dynamic Power Consumption
- $C_{PD} = 1.2pF$ Typical at 3.6V
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time. The hysteresis is typically 250mV at $V_{CC} = 3.0V$
- I_{OFF} Supports Partial-Power-Down Mode Operation
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless packages per JESD30E
 - DFN1410 denoted as X2-DFN1410-6
 - DFN1010 denoted as X2-DFN1010-6
 - DFN0910 denoted as X2-DFN0910-6
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

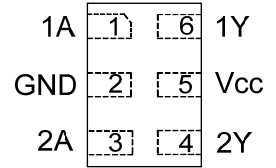
Pin Assignments

(Top View)



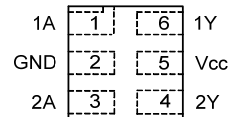
SOT363

(Top View)



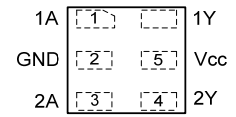
X2-DFN1410-6

(Top View)



X2-DFN1010-6

(Top View)

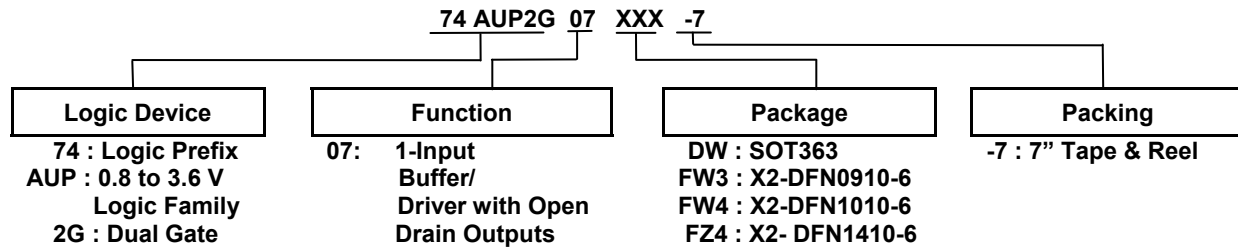


X2-DFN0910-6

Applications

- Suited for battery and low power needs
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Tablet Computers, E-readers
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Cell Phones, Personal Navigation / GPS
 - MP3 players, Cameras, Video Recorders

Ordering Information



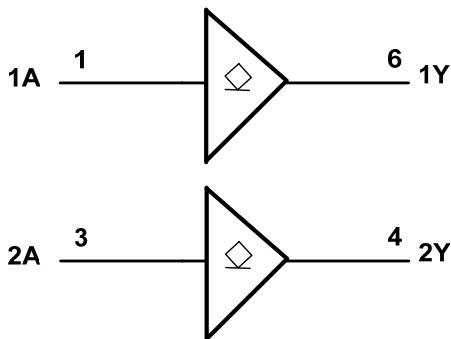
Part Number	Package Code	Package (Notes 4 & 5)	Package Size	7" Tape and Reel	
				Quantity	Part Number Suffix
74AUP2G07DW-7	DW	SOT363	2.0mm X 2.0mm X 1.1mm 0.65 mm lead pitch	3000/Tape & Reel	-7
74AUP2G07FW3-7	FW3	X2-DFN0910-6	0.9mm X 1.0mm X 0.35mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G07FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G07FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5 mm pad pitch	5000/Tape & Reel	-7

Notes: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 5. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

Pin Descriptions

Pin Name	Pin NO	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
V _{CC}	5	Supply Voltage
1Y	6	Data Output

Logic Diagram



Function Table

Inputs	Output
nA	nY
H	Z
L	L

Absolute Maximum Ratings (Notes 6,7) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +4.6	V
V _I	Input Voltage Range	-0.5 to +4.6	V
V _O	Voltage applied to Output in High or Low State	-0.5 to +4.6	V
I _{IK}	Input Clamp Current V _I < 0	-50	mA
I _{OK}	Output Clamp Current (V _O < 0)	-50	mA
I _O	Continuous Output Current (V _O = 0 to V _{CC})	±20	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

- Notes:
- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
 - Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Operating Voltage	0.8	3.6	V
V _I	Input Voltage	0	3.6	V
V _O	Output Voltage	0	3.6	V
I _{OL}	Low-Level Output Current	V _{CC} = 0.8V	20	μA
		V _{CC} = 1.1V	1.1	mA
		V _{CC} = 1.4V	1.7	
		V _{CC} = 1.65V	1.9	
		V _{CC} = 2.3V	3.1	
		V _{CC} = 3.0V	4	
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 0.8V to 3.6V	200	ns/V
T _A	Operating Free-Air Temperature	-40	+125	°C

- Note:
- Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V _{CC}	T _A = +25°C		T _A = -40 to +85°C		Unit
				Min	Max	Min	Max	
V _{IH}	High-Level Input Voltage	—	0.8V to 1.65V	0.80 X V _{CC}	—	0.80 X V _{CC}	—	V
		—	1.65V to 1.95V	0.65 X V _{CC}	—	0.65 X V _{CC}	—	
		—	2.3V to 2.7V	1.6	—	1.6	—	
		—	3.0V to 3.6V	2.0	—	2.0	—	
V _{IL}	Low-Level Input voltage	—	0.8V to 1.65V	—	0.30 X V _{CC}	—	0.30 X V _{CC}	V
		—	1.65V to 1.95V	—	0.35 X V _{CC}	—	0.35 X V _{CC}	
		—	2.3V to 2.7V	—	0.7	—	0.7	
		—	3.0V to 3.6V	—	0.9	—	0.9	
V _{OL}	Low-Level Output Voltage	I _{OL} = 20μA	0.8V to 3.6V	—	0.1	—	0.1	V
		I _{OL} = 1.1mA	1.1V	—	0.3 X V _{CC}	—	0.3 X V _{CC}	
		I _{OL} = 1.7mA	1.4V	—	0.31	—	0.37	
		I _{OL} = 1.9mA	1.65V	—	0.31	—	0.35	
		I _{OL} = 2.3mA	2.3V	—	0.31	—	0.33	
		I _{OL} = 3.1mA		—	0.44	—	0.45	
		I _{OL} = 2.7mA	3V	—	0.31	—	0.33	
		I _{OL} = 4mA		—	0.44	—	0.45	
I _I	Input Current	A or B Input, V _I = GND to 3.6V	0V to 3.6V	—	±0.1	—	±0.5	μA
I _{OZ}	Z State Leakage Current	V _O = 3.6V, V _I = 3.6V	3.6V	—	±0.1	—	±0.5	μA
I _{OFF}	Power Down Leakage Current	V _I or V _O = 0V to 3.6V	0V	—	±0.2	—	±0.6	μA
ΔI _{OFF}	Delta Power Down Leakage Current	V _I or V _O = 0V to 3.6V	0V to 0.2V	—	±0.2	—	±0.6	μA
I _{CC}	Supply Current	V _I = GND or V _{CC} , I _O = 0	0.8V to 3.6V	—	0.5	—	0.9	μA
ΔI _{CC}	Additional Supply Current	One input at V _{CC} -0.6V Other inputs at V _{CC} or GND	3.3V	—	40	—	50	μA

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V _{CC}	T _A = -40°C to +125°C		Unit
				Min	Max	
V _{IH}	High-Level Input Voltage	—	0.8V to 1.65V	0.80 X V _{CC}	—	V
		—	1.65V to 1.95V	0.70 X V _{CC}	—	
		—	2.3V to 2.7V	1.6	—	
		—	3.0V to 3.6V	2.0	—	
V _{IL}	Low-Level Input voltage	—	0.8V to 1.65V	—	0.25 X V _{CC}	V
		—	1.65V to 1.95V	—	0.30 X V _{CC}	
		—	2.3V to 2.7V	—	0.7	
		—	3.0V to 3.6V	—	0.9	
V _{OL}	Low-Level Output Voltage	I _{OL} = 20μA	0.8V to 3.6V	—	0.11	V
		I _{OL} = 1.1mA	1.1V	—	0.33 X V _{CC}	
		I _{OL} = 1.7mA	1.4V	—	0.41	
		I _{OL} = 1.9mA	1.65V	—	0.39	
		I _{OL} = 2.3mA	2.3V	—	0.36	
		I _{OL} = 3.1mA		—	0.50	
		I _{OL} = 2.7mA	3V	—	0.36	
		I _{OL} = 4mA		—	0.50	
I _I	Input Current	A or B Input, V _I = GND to 3.6V	0V to 3.6V	—	± 0.75	μA
I _{OZ}	Z State Leakage Current	V _O = 3.6V, V _I = 3.6V	3.6V	—	± 0.75	μA
I _{OFF}	Power Down Leakage Current	V _I or V _O = 0V to 3.6V	0V	—	± 0.75	μA
ΔI _{OFF}	Delta Power Down Leakage Current	V _I or V _O = 0V to 3.6V	0V to 0.2V	—	± 2.5	μA
I _{CC}	Supply Current	V _I = GND or V _{CC} , I _O = 0	0.8V to 3.6V	—	1.4	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} -0.6V Other inputs at V _{CC} or GND	3.3V	—	75	μA

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC}	Typ	Unit
C _{pd}	Power Dissipation Capacitance	f = 1MHz No Load	0.8V	0.5	pF
			1.2V ± 0.1V	0.6	
			1.5V ± 0.1V	0.7	
			1.8V ± 0.15V	0.7	
			2.5V ± 0.2V	1.0	
			3.3V ± 0.3V	1.2	
C _I	Input Capacitance	V _I = V _{CC} or GND	0V or 3.3V	2.0	pF
C _O	Output Capacitance	V _O = V _{CC} or GND	0V	2.0	pF

Switching Characteristics

 $C_L = 5\text{pF}$ see Figure 1

Parameter	From Input	TO OUTPUT	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	A	Y	0.8V		12.8						ns
			$1.2\text{V} \pm 0.1\text{V}$	2.6	5.8	11.3	2.3	12.5	2.3	15.9	
			$1.5\text{V} \pm 0.1\text{V}$	1.8	3.6	6.4	1.6	7.4	1.6	8.2	
			$1.8\text{V} \pm 0.15\text{V}$	1.5	2.9	5	1.4	5.9	1.4	6.5	
			$2.5\text{V} \pm 0.2\text{V}$	1.2	2.4	3.9	1.1	4.5	1.1	5	
			$3.3\text{V} \pm 0.3\text{V}$	0.9	3	3.5	0.8	3.9	0.8	4.3	

 $C_L = 10\text{pF}$ see Figure 1

Parameter	From Input	TO OUTPUT	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	A	Y	0.8V		14.5						ns
			$1.2\text{V} \pm 0.1\text{V}$	3.1	7	13.4	2.9	15.1	2.9	19.2	
			$1.5\text{V} \pm 0.1\text{V}$	2.3	4.8	7.5	2.1	8.7	2.1	10.5	
			$1.8\text{V} \pm 0.15\text{V}$	2	3.8	4.8	1.8	7	1.8	7.7	
			$2.5\text{V} \pm 0.2\text{V}$	1.6	3.1	4.6	1.5	5.4	1.5	6	
			$3.3\text{V} \pm 0.3\text{V}$	1.2	4.3	4.9	1.1	5.4	1.1	5.9	

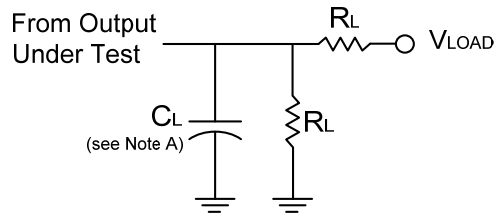
 $C_L = 15\text{pF}$ see Figure 1

Parameter	From Input	TO OUTPUT	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t_{pd}	A	Y	0.8V		16.2						ns
			$1.2\text{V} \pm 0.1\text{V}$	3.5	8.2	14.3	3.3	17.4	3.3	22.5	
			$1.5\text{V} \pm 0.1\text{V}$	2.6	6.2	8.6	2.4	10.5	2.4	13.7	
			$1.8\text{V} \pm 0.15\text{V}$	2.3	5	6.7	2.1	8	2.1	9.8	
			$2.5\text{V} \pm 0.2\text{V}$	2.1	3.9	5.1	1.8	6.1	1.8	6.8	
			$3.3\text{V} \pm 0.3\text{V}$	1.6	5.6	6.4	1.4	7.1	1.4	7.8	

 $C_L = 30\text{pF}$ see Figure 1

Parameter	From Input	TO OUTPUT	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	TYP	Min	Min	Max	Min	Max	
t_{pd}	A	Y	0.8V		19.8						ns
			$1.2\text{V} \pm 0.1\text{V}$	4.8	9.8	18.4	4.4	18.4	4.4	25.8	
			$1.5\text{V} \pm 0.1\text{V}$	3.6	8.2	13.9	3.2	13.9	3.2	18	
			$1.8\text{V} \pm 0.15\text{V}$	3.2	7.8	12.2	2.9	12.2	2.9	15.2	
			$2.5\text{V} \pm 0.2\text{V}$	2.4	7.5	9.9	2.6	9.9	2.6	11.4	
			$3.3\text{V} \pm 0.3\text{V}$	1.8	9.2	10.6	2.1	11.6	2.1	12.8	

Parameter Measurement Information



TEST	Condition
t_{PLZ} (see Notes D and E)	Vload
t_{PZL} (see Notes D and F)	Vload

V _{CC}	Inputs		V _M	V _{LOAD}	C _L	R _L	V _Δ
	V _I	t _r /t _f					
0.8V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.1V
1.2V±0.1V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.1V
1.5V±0.1V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.15V
1.8V±0.15V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.15V
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.15V
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	5, 10, 15, 30pF	5 kΩ	0.3V

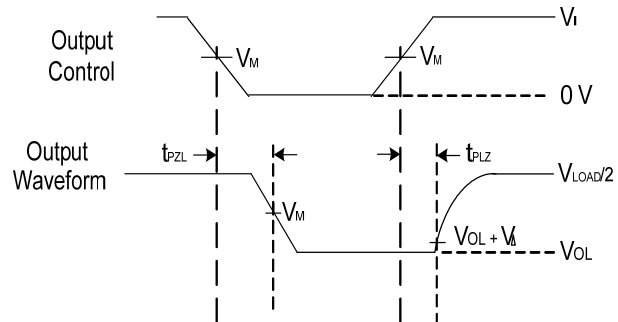
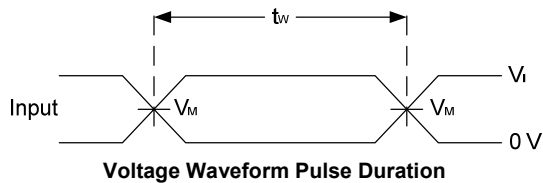
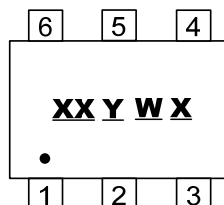


Figure 1 Load Circuit and Voltage Waveforms

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
 - C. The inputs are measured one at a time with one transition per measurement.
 - D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD} .
 - E. t_{PZL} is measured at V_M .
 - D. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.

Marking Information

(1) SOT363

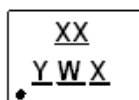


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal Code

Part Number	Package	Identification Code
74AUP2G07DW-7	SOT363	SP

(2) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)



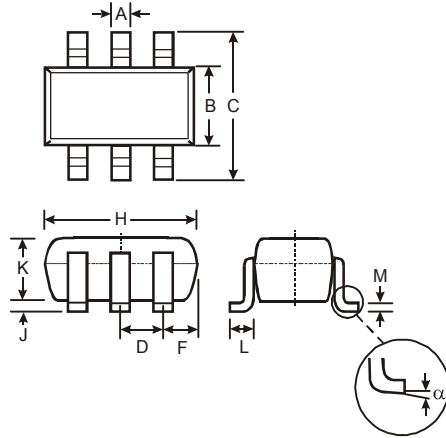
XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74AUP2G07FZ4	X2-DFN1410-6	RP
74AUP2G07FW4	X2-DFN1010-6	SP
74AUP2G07FW3	X2-DFN0910-6	MP

Package Outline Dimensions (All dimensions in mm.)

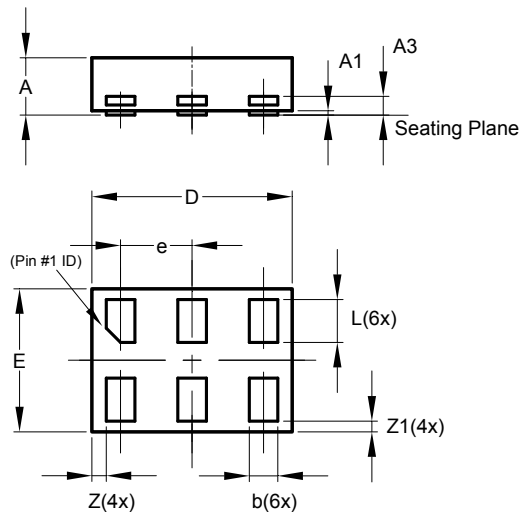
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(1) Package Type SOT363



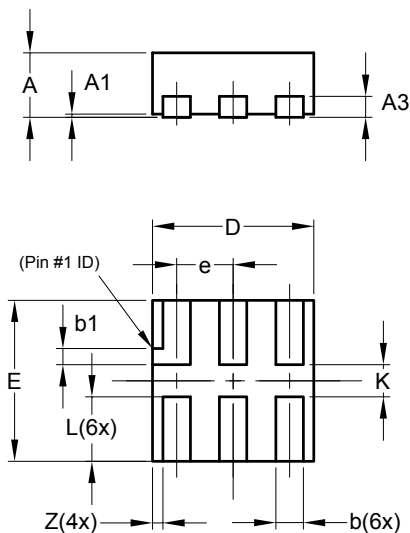
SOT363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

(2) Package Type X2-DFN1410-6



X2-DFN1410-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
e	—	—	0.50
L	0.25	0.35	0.30
Z	—	—	0.10
Z1	0.045	0.105	0.075
All Dimensions in mm			

(3) Package Type: X2-DFN1010-6

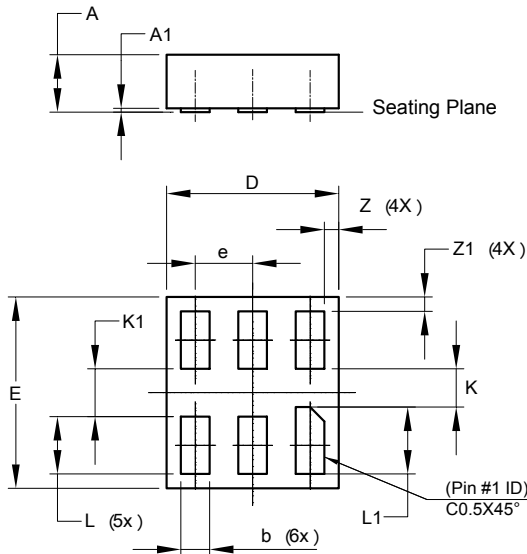


X2-DFN1010-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
E	0.95	1.05	1.00
e	—	—	0.35
L	0.35	0.45	0.40
K	0.15	—	—
Z	—	—	0.065
All Dimensions in mm			

Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(4) Package Type: X2-DFN0910-6

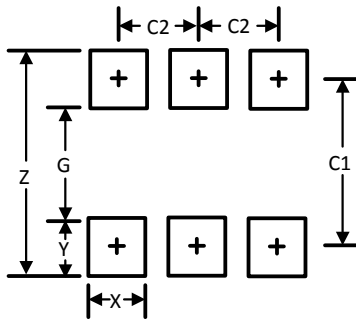


X2-DFN0910-6			
Dim	Min	Max	Typ
A	-	0.35	0.30
A1	0	0.03	0.02
b	0.10	0.20	0.15
D	0.85	0.95	0.90
E	0.95	1.05	1.00
e	-	-	0.30
K	0.20	-	-
K1	0.25	-	-
L	0.25	0.35	0.30
L1	0.30	0.40	0.35
Z	-	-	0.075
Z1	-	-	0.075
All Dimensions in mm			

Suggested Pad Layout

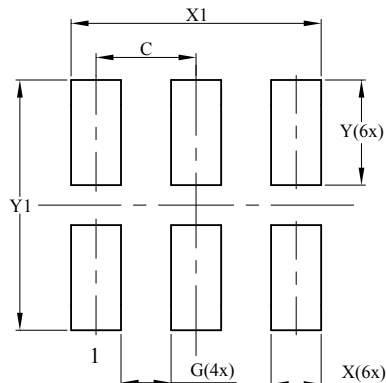
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(1) Package Type SOT363



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

(2) Package Type X2-DFN1410-6

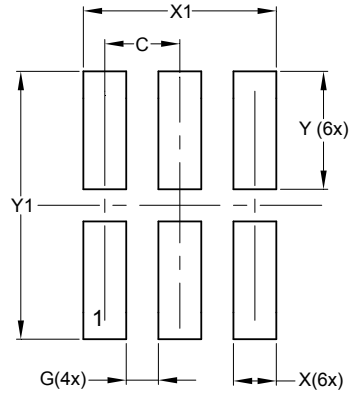


Dimensions	Value (in mm)
C	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

Suggested Pad Layout

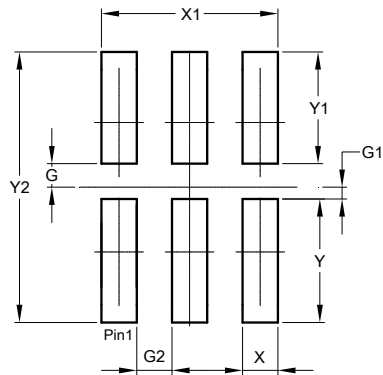
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(3) Package Type: X2-DFN1010-6



Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
X	0.150
X1	0.750
Y	0.525
Y1	0.475
Y2	1.150

(4) Package Type: X2-DFN0910-6



Dimensions	Value (in mm)
C	0.350
G	0.150
X	0.200
X1	0.900
Y	0.550
Y1	1.250

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